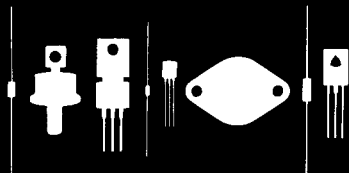


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145 Adams Avenue
Hauppauge, New York 11788



2N1479
2N1480
2N1481
2N1482

NPN SILICON TRANSISTOR

JEDEC TO-39 CASE

DESCRIPTION

The CENTRAL SEMICONDUCTOR 2N1479 series types are silicon NPN transistors manufactured by the epitaxial planar process, mounted in a hermetically sealed metal case designed for switching and amplifier applications.

MAXIMUM RATINGS ($T_C=25^\circ\text{C}$ unless otherwise noted)

	SYMBOL	2N1479 2N1481	2N1480 2N1482	UNIT
Collector-Base Voltage	V _{CB0}	60	100	V
Collector-Emitter Voltage	V _{CEV}	60	100	V
Collector-Emitter Voltage	V _{CEO}	40	55	V
Emitter-Base Voltage	V _{EB0}	6.0	6.0	V
Collector Current	I _C	1.5	1.5	A
Base Current	I _B	1.0	1.0	A
Power Dissipation	P _D	5.0	5.0	W
Operating and Storage Junction Temperature	T _J , T _{STG}	-65 TO +200		$^\circ\text{C}$
Thermal Resistance	θ_{JC}	35		$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS ($T_C=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	2N1479		2N1480		2N1481		2N1482		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
I _{CB0}	V _{CB} =30V		10		10		10		10	μA
I _{CB0}	V _{CB} =30V, $T_C=150^\circ\text{C}$		500		500		500		500	μA
I _{EB0}	V _{EB} =6.0V		10		10		10		10	μA
BV _{CEV}	V _{EB} =1.5V, I _C =0.25mA	60		100		60		100		V
BV _{CEO}	I _C =50mA	40		55		40		55		V
V _{CE} (SAT)	I _C =200mA, I _B =10mA		-		-		1.4		1.4	V
V _{CE} (SAT)	I _C =200mA, I _B =20mA		1.4		1.4		-		-	V
V _{BE} (ON)	V _{CE} =4.0V, I _C =200mA		3.0		3.0		3.0		3.0	V
h _{FE}	V _{CE} =4.0V, I _C =200mA	20	60	20	60	35	100	35	100	
h _{fe}	V _{CE} =4.0V, I _C =5.0mA	50	TYP	50	TYP	50	TYP	50	TYP	
t _{ON}	I _C =200mA, I _{B1} =20mA, I _{B2} =85mA	1.2	TYP	1.2	TYP	1.2	TYP	1.2	TYP	μs
t _{OFF}	I _C =200mA, I _{B1} =20mA, I _{B2} =85mA	1.6	TYP	1.6	TYP	1.6	TYP	1.6	TYP	μs
C _{ob}	V _{CB} =40V	150	TYP	150	TYP	150	TYP	150	TYP	pF
f _{αb}	V _{CB} =28V, I _C =5.0mA	1.5	TYP	1.5	TYP	1.5	TYP	1.5	TYP	MHz

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